Transistors

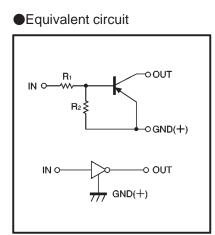
Digital transistors (built-in resistors) DTB123YK/DTB123YC/DTB123YS

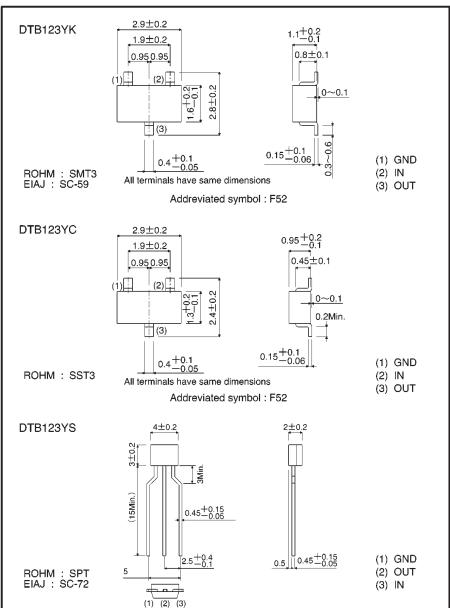
Features

- Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit).
- The bias resistors consist of thinfilm resistors with complete isolation to allow positive biasing of the input. They also have the advantage of almost completely eliminating parasitic effects.
- Only the on/off conditions need to be set for operation, making device design easy.

Structure PNP digital transistor

(Built-in resistor type)





External dimensions (Units: mm)



• Absolute maximum ratings (Ta = 25° C)

Parameter	Symbol	Limits(DTB123Y			Unit
		К	С	S	Unit
Supply voltage	Vcc		V		
Input voltage	Vin	_	V		
Output current	lc	-500			mA
Power dissipation	Pd	200		300	mW
Junction temperature	Tj	150			Ĵ
Storage temperature	Tstg	-55~+150			C

•Electrical characteristics (Ta = 25° C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions	
Input voltage	VI(off)	_	-	-0.3		$V_{CC} = -5V$, $I_{O} = -100 \mu A$	
	VI(on)	-2	_	_	V	Vo=-0.3V, Io=-20mA	
Output voltage	VO(on)	—	-0.1	-0.3	V	lo/l=-50mA/-2.5mA	
Input current	h	_	_	-3.6	mA	VI=-5V	
Output current	IO(off)	—	-	-0.5	μA	Vcc=-50V, VI=0V	
DC current gain	Gi	56	-	_	_	Vo=-5V, lo=-50mA	
Input resistance	Rı	1.54	2.2	2.86	kΩ	—	
Resistance ratio	R2/R1	3.6	4.5	5.5	_	_	
Transition frequency	fт	—	200	-	MHz	Vce=-10V, le=5mA, f=100MHz *	

* Transition frequency of the device

Packaging specifications

	Package	SMT3	SST3	SPT
	Packaging type	Taping	Taping	Taping
	Code		T116	TP
Part No.	Basic ordering unit (pieces)	3000	3000	5000
DTB123YK		0		
DTB123YC		—	0	_
DTB123YS		_	_	0



Transistors

Electrical characteristic curves

